



N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS} (@ Tj Max)	Rds(on)	I _D Tc = +25°С	
1000V	$7\Omega@V_{GS} = 10V$	2.5A	

Description

This new generation MOSFET features low on-resistance and fast switching, making it ideal for high efficiency power management applications.

Applications

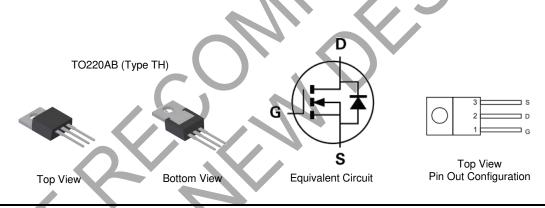
- Motor Control
- Backlighting
- **DC-DC Converters**
- Power Management Functions

Features

- Low Input Capacitance
- High BV_{DSS} Rating for Power Application
- Low Input/Output Leakage
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Case: TO220AB
- Case Material: Molded Plastic, "Green" Molding Compound, UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Terminal Connections: See Diagram Below
- Weight: 1.85 grams (Approximate)



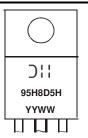
Ordering Information (Note 4)

Part Number Case	Packaging
DMN95H8D5HCT TO220AB (Type TH)	50 Pieces/Tube

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Notes: l ead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>
4 For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



) | | = Manufacturer's Marking 95H8D5H = Product Type Marking Code YYWW = Date Code Marking YY or <u>YY</u> = Last Two Digits of Year (ex: 20 = 2020) WW or WW = Week Code (01 to 53)



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic			Symbol Value		Units
Drain-Source Voltage			VDSS	950	V
Gate-Source Voltage			V _{GSS}	±30	V
Continuous Drain Current V _{GS} = 10V	Steady State	Tc = +25°C T _C = +100°C	ID	2.5 1.5	А
Maximum Body Diode Forward Current (Note 5)			ls	3	A
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I _{DM}	3	A
Avalanche Current, L = 60mH (Note 7)			I _{AS}	1.8	A
Avalanche Energy, L = 60mH (Note 7)			Eas	97	mJ
Peak Diode Recovery dv/dt			dv/dt	3.3	V/ns
		I			<u>v/115</u>

Thermal Characteristics

Characteristic		Symbol	Value	Units
Total Power Dissipation	$\frac{T_{C} = +25^{\circ}C}{T_{C} = +100^{\circ}C}$	PD	125 50	W
Thermal Resistance, Junction to Ambient (Note 6)		Reja	50	°C/W
Thermal Resistance, Junction to Case		Rejc	1	C/ W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

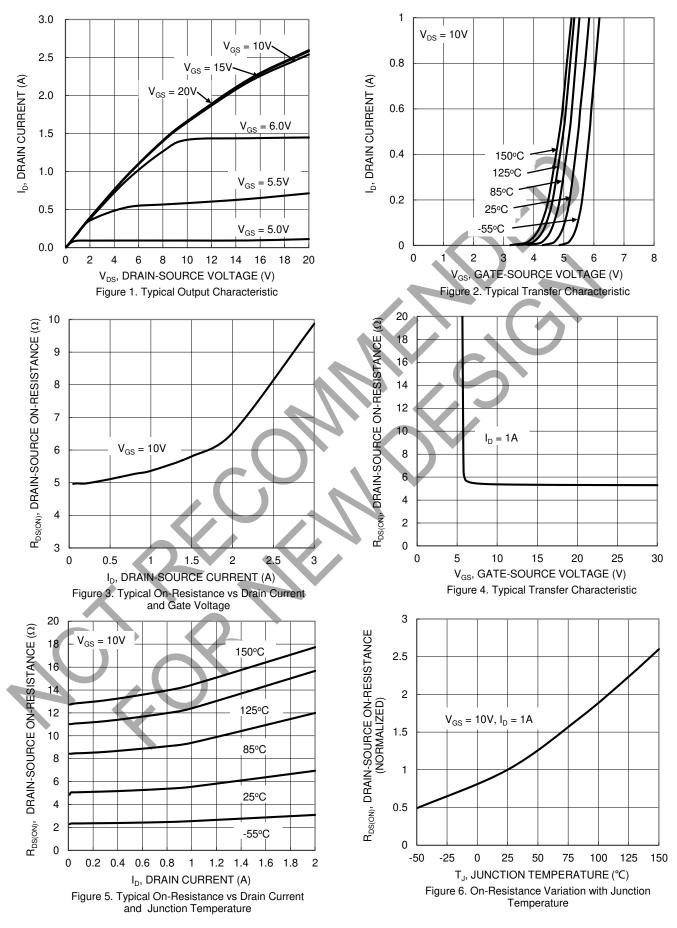
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	Joyinbor	WIIII	Тур	IMIAA	Unit	Test condition	
Drain-Source Breakdown Voltage	BVpss	950			V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	—	1	μA	$V_{DS} = 950V$, $V_{GS} = 0V$	
Gate-Source Leakage	Igss	-	—	100	nA	$V_{GS} = \pm 30V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	3.0	4.0	5.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	RDS(ON)	_	5.5	7	Ω	VGS = 10V, ID = 1A	
Diode Forward Voltage	Vsd	—	0.84	1.2	V	$V_{GS} = 0V$, $I_S = 2A$	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	Ciss	—	470	—		V _{DS} = 25V, f = 1.0MHz, V _{GS} = 0	
Output Capacitance	Coss	-	45	—	pF		
Reverse Transfer Capacitance	Crss	—	0.6	_			
Gate Resistance	Rg	-	1.2	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge	Qg	—	7.9	_			
Gate-Source Charge	Qgs	-	2.5	—	nC	$V_{DD} = 720V, I_D = 2A,$ $V_{GS} = 10V$	
Gate-Drain Charge	Q _{gd}	—	2.9	—			
Turn-On Delay Time	tD(ON)	—	16	—			
Turn-On Rise Time	t _R	—	21	—		$\label{eq:VDD} \begin{array}{l} V_{DD} = 450V, R_G = 25\Omega, I_D = 2A, \\ V_{GS} = 10V \end{array}$	
Turn-Off Delay Time	tD(OFF)	—	17.6	—	ns		
Turn-Off Fall Time	tF	—	17	—			
Body Diode Reverse Recovery Time	t _{RR}	—	375	_	ns	dl/dt = 100A/µs, V _{DS} = 100V,	
Body Diode Reverse Recovery Charge	Qrr	—	2.9	_	μC	$I_F = 2A$	

Notes:

Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Guaranteed by design. Not subject to production testing.
 Short duration pulse test used to minimize self-heating effect.

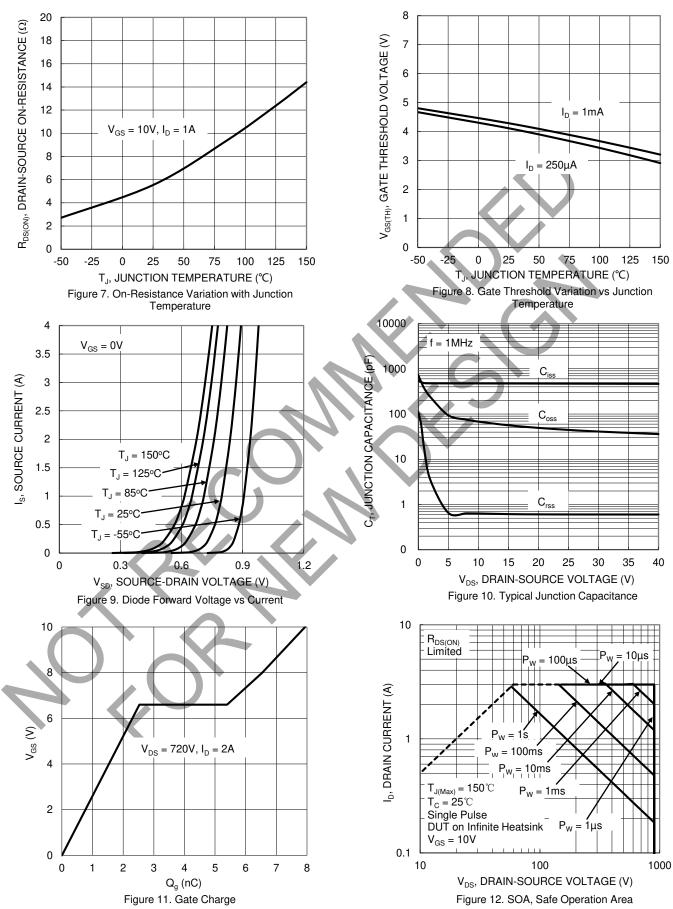


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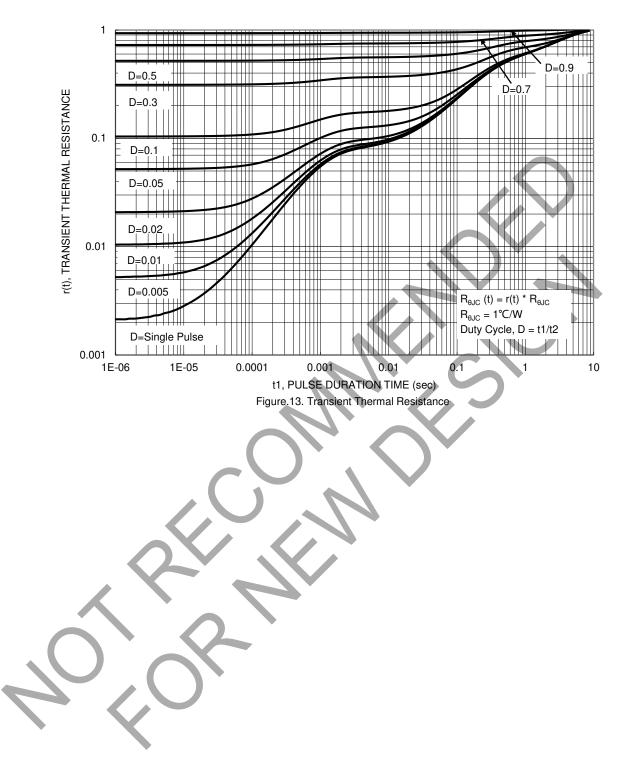


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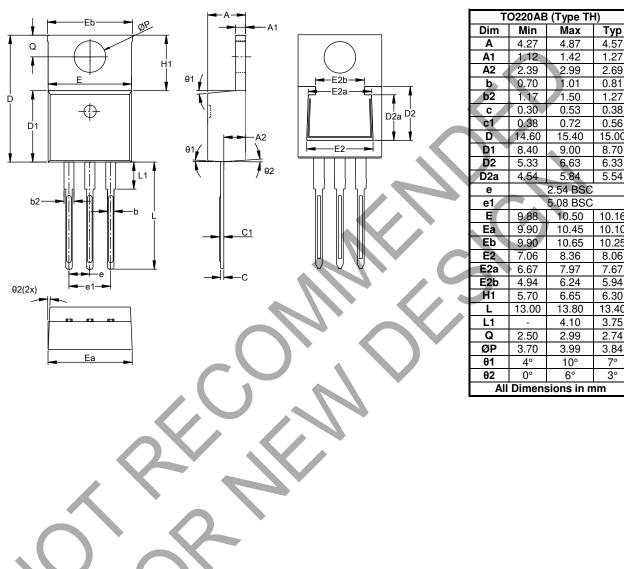






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



TO220AB (Type TH)

DIM	IVIIN	Max	тур			
Α	4.27	4.87	4.57			
A1	1.12	1.42	1.27			
A2	2.39	2.99	2.69			
b	0.70	1.01	0.81			
b2	1.17	1.50	1.27			
C	0.30	0.53	0.38			
c1	0.38	0.72	0.56			
D	14.60	15.40	15.00			
D1	8.40	9.00	8.70			
D 2	5.33	6.63	6.33			
D2a	4.54	5.84	5.54			
e	2.54 BSC					
e1		5.08 BSC				
E	9.88	10.50	10.16			
Ea	9.90	10.45	10.10			
Eb	9.90	10.65	10.25			
E2	7.06	8.36	8.06			
E2a	6.67	7.97	7.67			
E2b	4.94	6.24	5.94			
H1	5.70	6.65	6.30			
L	13.00	13.80	13.40			
	-	4.10	3.75			
Q	2.50	2.99	2.74			
ØP	3.70	3.99	3.84			
θ1	4°	10°	7°			
θ2	0°	6°	3°			
All	All Dimensions in mm					



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